



<DIODE Modules>

RM1400HA-24S

HIGH POWER SWITCHING USE
INSULATED TYPE



single pack

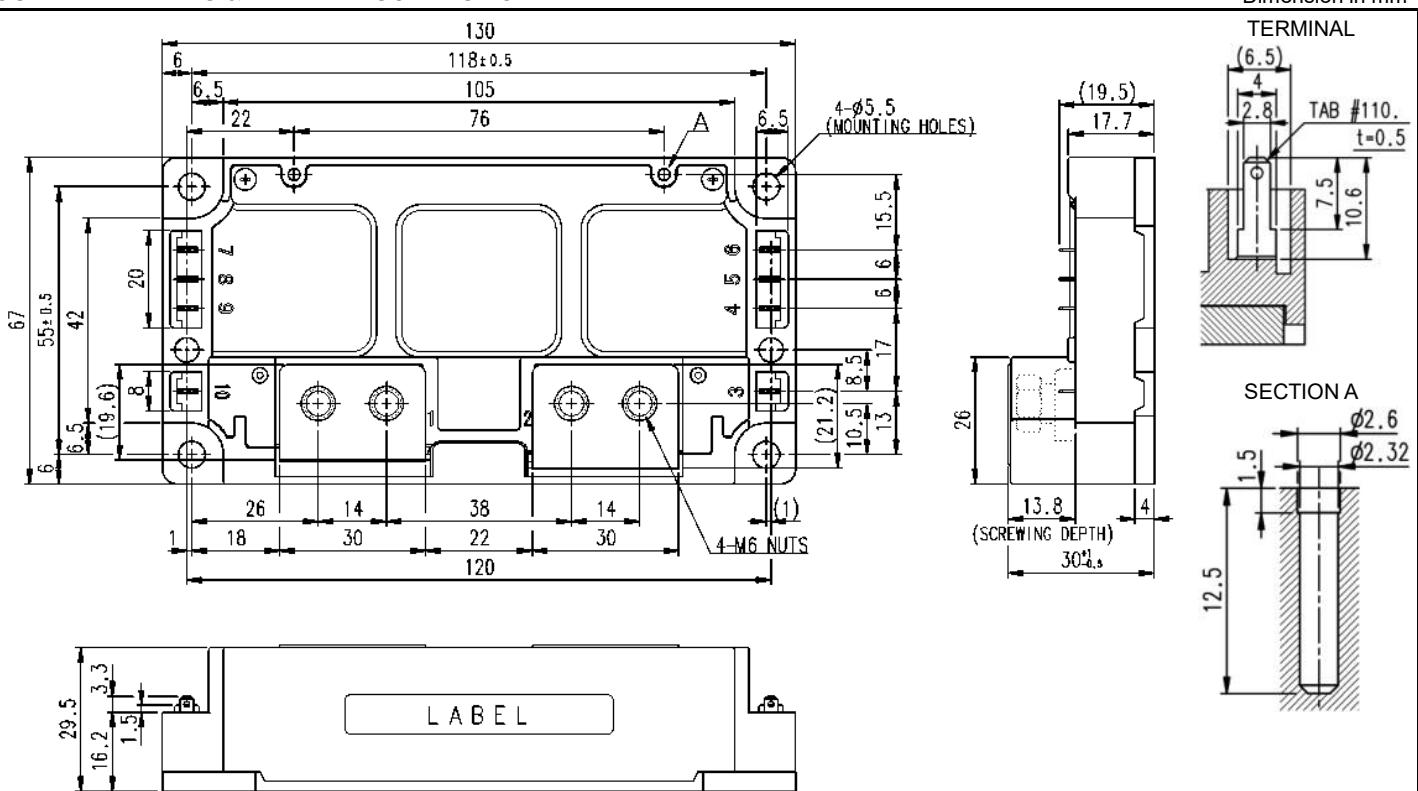
Forward current I_{DC} 1400 A
 Repetitive peak reverse voltage V_{RRM} 1200 V
 Maximum junction temperature T_{vjmax} 175 °C
 •Flat base Type
 •Copper base plate
 •RoHS Directive compliant
 •Recognized under UL1557, File E323585

APPLICATION

AC Motor Control, Motion/Servo Control, Power supply, Photovoltaic power, Wind power, etc.

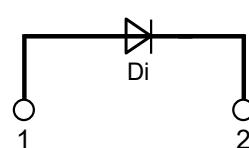
OUTLINE DRAWING & INTERNAL CONNECTION

Dimension in mm



INTERNAL CONNECTION

7 ○	○ 6
8 ○	○ 5
9 ○	○ 4
10 ○	○ 3



Terminal code

- 1: A
- 2: K
- 3: NC
- 4: NC
- 5: NC
- 6: NC
- 7: NC
- 8: NC
- 9: NC
- 10: NC

Tolerance otherwise specified		
Division of Dimension	Tolerance	
0.5	to 3	±0.2
over 3	to 6	±0.3
over 6	to 30	±0.5
over 30	to 120	±0.8
over 120	to 400	±1.2
over 400	to 1000	±2.0
over 1000	to 2000	±3.0
over 2000	to 4000	±4.0

MAXIMUM RATINGS ($T_{vj}=25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Symbol	Item	Conditions	Rating	Unit
V_{RRM}	Repetitive peak reverse voltage	-	1200	V
V_{RSM}	Non-repetitive peak reverse voltage	-	1200	V
$V_{R(DC)}$	Reverse DC blocking voltage	-	960	V
I_{DC}	Forward current	DC (Note1)	1400	A
I_{FSM}	Surge non-repetitive forward current	1 cycle of half wave at 60 Hz, peak value, $T_{vj}=25\text{ }^{\circ}\text{C}$ start, $V_{RM}=0\text{ V}$	3526	A
I^2t	Current square time for fusing	$t_w=8.3\text{ ms}$, $T_{vj}=25\text{ }^{\circ}\text{C}$ start, Value for one cycle of surge current	5.16×10^4	A^2s
V_{isol}	Isolation voltage	Terminals to base plate, RMS, $f=60\text{ Hz}$, AC 1 min	4000	V
T_{vjmax}	Maximum junction temperature	Instantaneous event (overload)	175	$^{\circ}\text{C}$
T_{Cmax}	Maximum case temperature	(Note2)	125	
T_{vjop}	Operating junction temperature	Continuous operation (under switching)	-40 ~ +150	$^{\circ}\text{C}$
T_{stg}	Storage temperature	-	-40 ~ +125	

ELECTRICAL CHARACTERISTICS ($T_{vj}=25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Symbol	Item	Conditions	Limits			Unit
			Min.	Typ.	Max.	
I_{RRM}	Reverse current	$V_R=V_{RRM}$, $T_{vj}=125\text{ }^{\circ}\text{C}$	-	-	1.0	mA
V_F (Terminal)	Forward voltage	$I_F=1400\text{ A}$, $V_{GE}=15\text{ V}$, Refer to the figure of test circuit (Note3)	$T_{vj}=25\text{ }^{\circ}\text{C}$	-	2.03	2.48
			$T_{vj}=125\text{ }^{\circ}\text{C}$	-	2.08	-
			$T_{vj}=150\text{ }^{\circ}\text{C}$	-	2.08	-
V_F (Chip)	Forward voltage	$I_F=1400\text{ A}$ (Note3)	$T_{vj}=25\text{ }^{\circ}\text{C}$	-	1.75	2.20
			$T_{vj}=125\text{ }^{\circ}\text{C}$	-	1.80	-
			$T_{vj}=150\text{ }^{\circ}\text{C}$	-	1.80	-
t_{rr}	Reverse recovery time	$V_{CC}=600\text{ V}$, $I_F=1400\text{ A}$, $V_{GE}=\pm 15\text{ V}$, $-\text{d}iF/\text{d}t=11\text{kA}/\mu\text{s}$, Inductive load	-	-	500	ns
Q_{rr}	Reverse recovery charge		-	150	-	μC
E_{rr}	Reverse recovery energy per pulse		-	104	-	mJ
$R_{AA'+KK'}$	Internal lead resistance	Main terminals-chip, $T_c=25\text{ }^{\circ}\text{C}$ (Note2)	-	0.2	-	$\text{m}\Omega$

THERMAL RESISTANCE CHARACTERISTICS

Symbol	Item	Conditions	Limits			Unit
			Min.	Typ.	Max.	
$R_{th(j-c)}$	Thermal resistance	Junction to case (Note2)	-	-	32	K/kW
$R_{th(c-s)}$	Contact thermal resistance	Case to heat sink, Thermal grease applied (Note2, 4)	-	18	-	K/kW

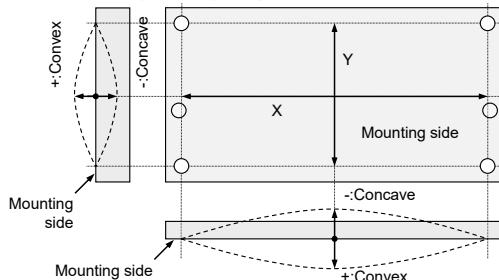
MECHANICAL CHARACTERISTICS

Symbol	Item	Conditions	Limits			Unit
			Min.	Typ.	Max.	
M_t	Mounting torque	Main terminals M 6 screw	3.5	4.0	4.5	$\text{N}\cdot\text{m}$
M_s	Mounting torque	Mounting to heat sink M 5 screw	2.5	3.0	3.5	$\text{N}\cdot\text{m}$
d_s	Creepage distance	Terminal to terminal	22.0	-	-	mm
		Terminal to base plate	21.9	-	-	
d_a	Clearance	Terminal to terminal	16.5	-	-	mm
		Terminal to base plate	12.5	-	-	
e_c	Flatness of base plate	On the centerline X, Y (Note5)	-50	-	+100	μm
m	mass	-	-	490	-	g

RM1400HA-24S**HIGH POWER SWITCHING USE
INSULATED TYPE**

*: This product is compliant with the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment (RoHS) directive 2011/65/EU.
Note1. Junction temperature (T_{VJ}) should not exceed T_{VJmax} rating.

2. Case temperature (T_c) and heat sink temperature (T_s) are defined on the each surface (mounting side) of base plate and heat sink just under the chips.
Refer to the figure of chip location.
3. Pulse width and repetition rate should be such as to cause negligible temperature rise. Refer to the figure of test circuit.
4. Typical value is measured by using thermally conductive grease of $\lambda=0.9\text{ W}/(\text{m}\cdot\text{K})/D_{(C-S)}=100\text{ }\mu\text{m}$.
5. The base plate (mounting side) flatness measurement points (X, Y) are shown in the following figure.



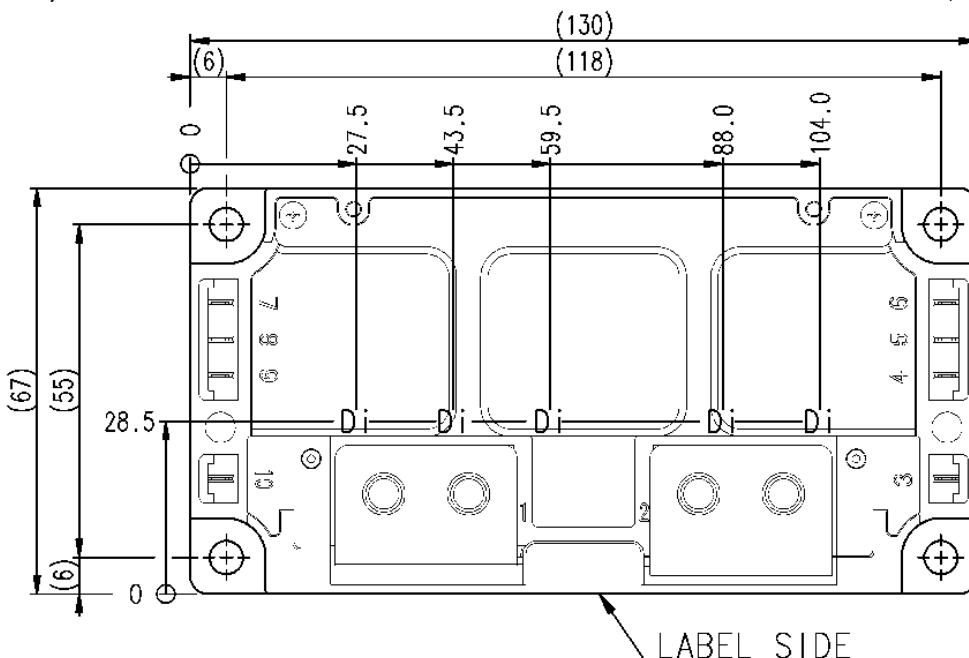
6. Use the following screws when mounting the printed circuit board (PCB) on the standoffs.

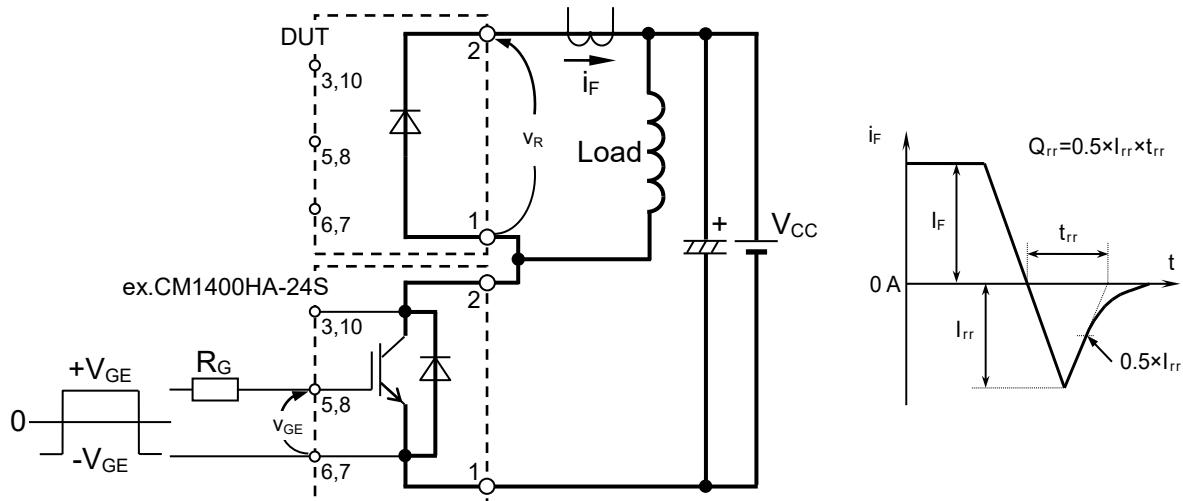
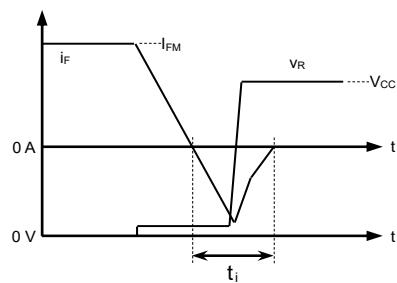
The length of the screw depends on the PCB thickness (11.0).

Type	Size	Tightening torque	Recommended tightening method
(1) PT®	K25×8	$0.55 \pm 0.055\text{ N}\cdot\text{m}$	by handwork (equivalent to 30 r/min by mechanical screw driver) ~ 600 r/min (by mechanical screw driver)
(2) PT®	K25×10	$0.85 \pm 0.085\text{ N}\cdot\text{m}$	
(3) DELTA PT®	25×8	$0.55 \pm 0.055\text{ N}\cdot\text{m}$	
(4) DELTA PT®	25×10	$0.85 \pm 0.085\text{ N}\cdot\text{m}$	
(5) B1 tapping screw	$\varphi 2.6 \times 10$ or $\varphi 2.6 \times 12$	$0.85 \pm 0.085\text{ N}\cdot\text{m}$	

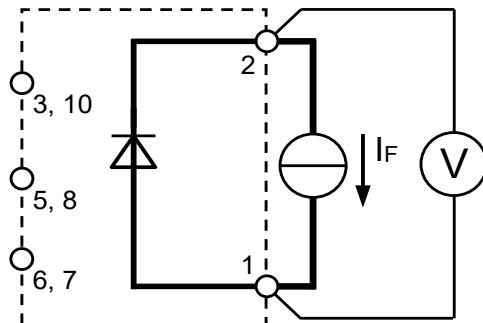
CHIP LOCATION (Top view)

Dimension in mm, tolerance: $\pm 1\text{ mm}$

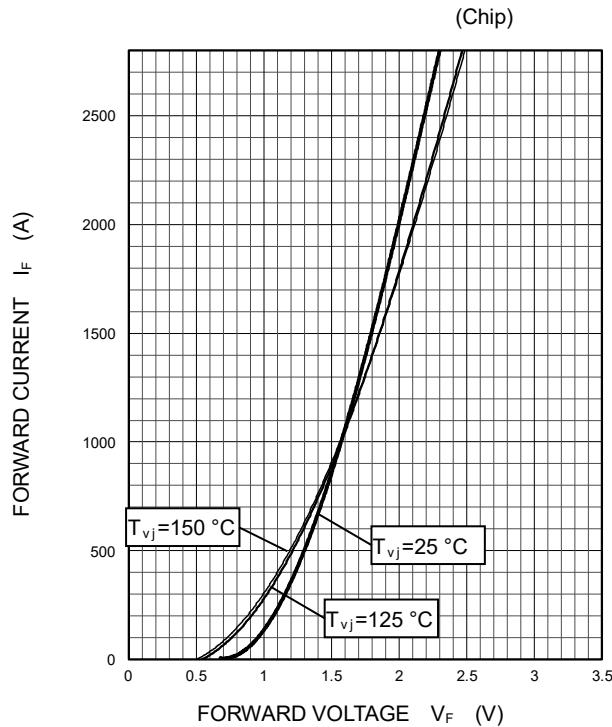
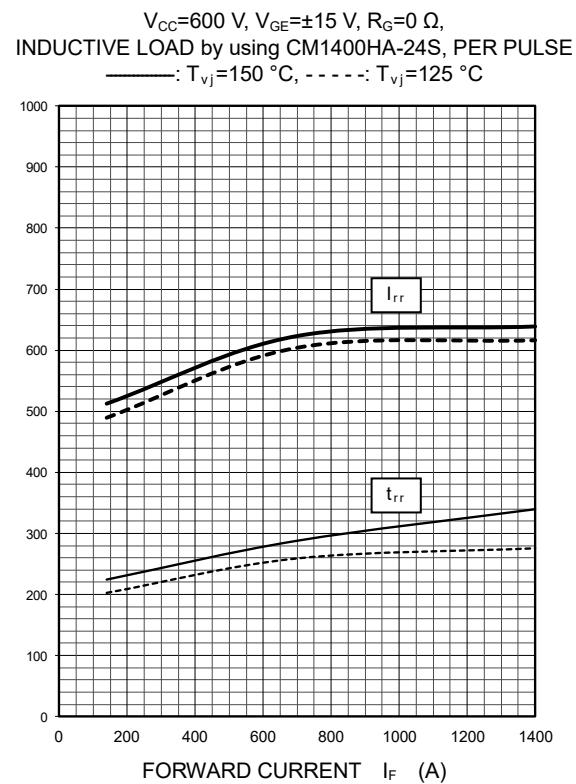


TEST CIRCUIT AND WAVEFORMSt_{rr}, Q_{rr} characteristics test circuit and waveforms

Reverse recovery energy test waveforms (Integral time instruction drawing)

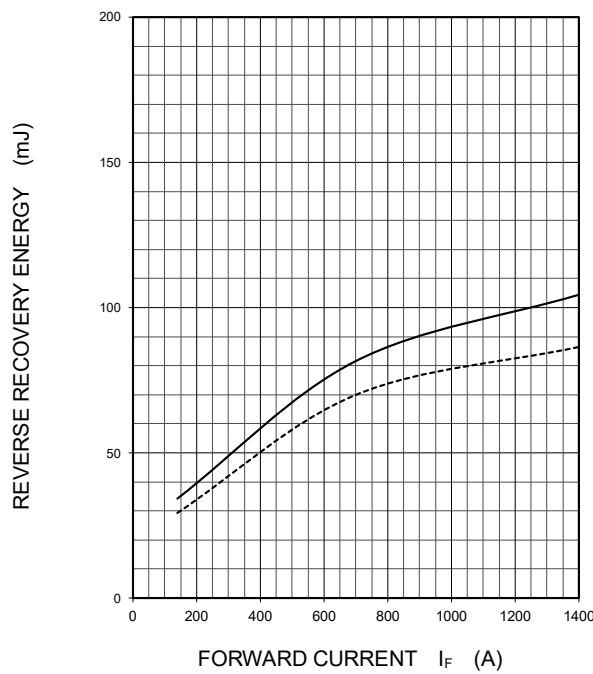
TEST CIRCUITV_{EC} characteristics test circuit

PERFORMANCE CURVES

FORWARD CHARACTERISTICS
(TYPICAL)REVERSE RECOVERY CHARACTERISTICS
(TYPICAL)HALF-BRIDGE SWITCHING CHARACTERISTICS
(TYPICAL)

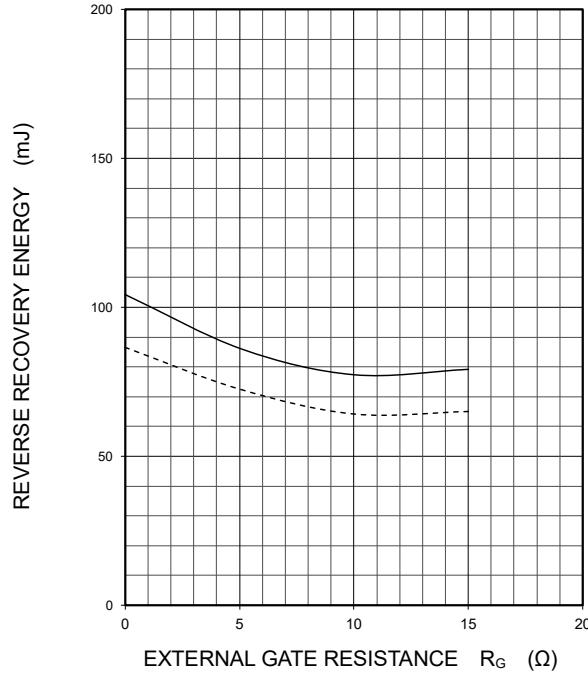
$V_{CC}=600\text{ V}$, $V_{GE}=\pm 15\text{ V}$, $R_G=0\text{ }\Omega$,
INDUCTIVE LOAD by using CM1400HA-24S, PER PULSE

—: $T_{vj}=150\text{ }^{\circ}\text{C}$, - - -: $T_{vj}=125\text{ }^{\circ}\text{C}$

HALF-BRIDGE SWITCHING CHARACTERISTICS
(TYPICAL)

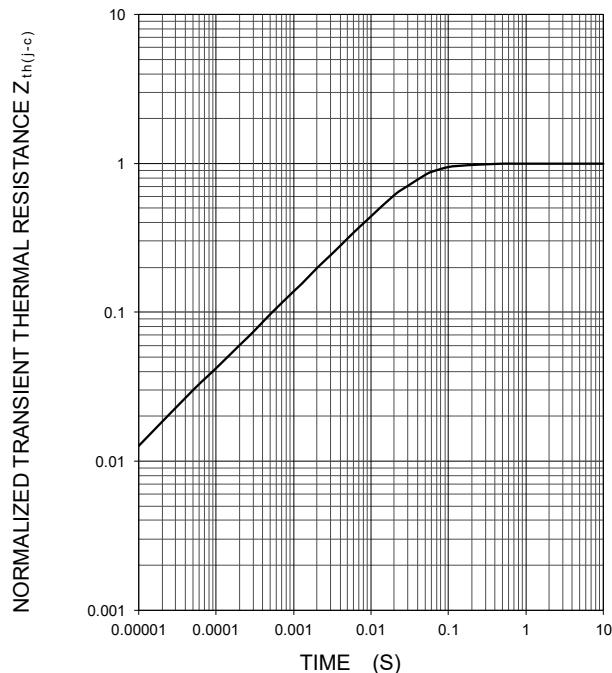
$V_{CC}=600\text{ V}$, $V_{GE}=\pm 15\text{ V}$, $I_F=1400\text{ A}$,
INDUCTIVE LOAD by using CM1400HA-24S, PER PULSE

—: $T_{vj}=150\text{ }^{\circ}\text{C}$, - - -: $T_{vj}=125\text{ }^{\circ}\text{C}$



PERFORMANCE CURVES**TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS
(MAXIMUM)**

Single pulse, $T_c=25\text{ }^{\circ}\text{C}$
 $R_{th(j-c)}=32\text{ K/kW}$



Note: The characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Important Notice

The information contained in this datasheet shall in no event be regarded as a guarantee of conditions or characteristics. This product has to be used within its specified maximum ratings, and is subject to customer's compliance with any applicable legal requirement, norms and standards.

Except as otherwise explicitly approved by Mitsubishi Electric Corporation in a written document signed by authorized representatives of Mitsubishi Electric Corporation, our products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.

In usage of power semiconductor, there is always the possibility that trouble may occur with them by the reliability lifetime such as Power Cycle, Thermal Cycle or others, or when used under special circumstances (e.g. condensation, high humidity, dusty, salty, highlands, environment with lots of organic matter / corrosive gas / explosive gas, or situations which terminals of semiconductor products receive strong mechanical stress). Therefore, please pay sufficient attention to such circumstances. Further, depending on the technical requirements, our semiconductor products may contain environmental regulation substances, etc. If there is necessity of detailed confirmation, please contact our nearest sales branch or distributor.

The contents or data contained in this datasheet are exclusively intended for technically trained staff. Customer's technical departments should take responsibility to evaluate the suitability of Mitsubishi Electric Corporation product for the intended application and the completeness of the product data with respect to such application. In the customer's research and development, please evaluate it not only with a single semiconductor product but also in the entire system, and judge whether it's applicable. As required, pay close attention to the safety design by installing appropriate fuse or circuit breaker between a power supply and semiconductor products to prevent secondary damage. Please also pay attention to the application note and the related technical information.

Keep safety first in your circuit designs!

Mitsubishi Electric Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of non-flammable material or (iii) prevention against any malfunction or mishap.

Notes regarding these materials

- These materials are intended as a reference to assist our customers in the selection of the Mitsubishi Electric Semiconductor product best suited to the customer's application; they do not convey any license under any intellectual property rights, or any other rights, belonging to Mitsubishi Electric Corporation or a third party.
- Mitsubishi Electric Corporation assumes no responsibility for any damage, or infringement of any third-party's rights, originating in the use of any product data, diagrams, charts, programs, algorithms, or circuit application examples contained in these materials.
- All information contained in these materials, including product data, diagrams, charts, programs and algorithms represents information on products at the time of publication of these materials, and are subject to change by Mitsubishi Electric Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact Mitsubishi Electric Corporation or an authorized Mitsubishi Electric Semiconductor product distributor for the latest product information before purchasing a product listed herein.

The information described here may contain technical inaccuracies or typographical errors. Mitsubishi Electric Corporation assumes no responsibility for any damage, liability, or other loss rising from these inaccuracies or errors.

Please also pay attention to information published by Mitsubishi Electric Corporation by various means, including the Mitsubishi Electric Semiconductor home page (<http://www.MitsubishiElectric.com/semiconductors/>).

- When using any or all of the information contained in these materials, including product data, diagrams, charts, programs, and algorithms, please be sure to evaluate all information as a total system before making a final decision on the applicability of the information and products. Mitsubishi Electric Corporation assumes no responsibility for any damage, liability or other loss resulting from the information contained herein.
- Mitsubishi Electric Corporation semiconductors are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact Mitsubishi Electric Corporation or an authorized Mitsubishi Electric Semiconductor product distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.
- The prior written approval of Mitsubishi Electric Corporation is necessary to reprint or reproduce in whole or in part these materials.
- If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination.

Any diversion or re-export contrary to the export control laws and regulations of Japan and/or the country of destination is prohibited.

- Please contact Mitsubishi Electric Corporation or an authorized Mitsubishi Electric Semiconductor product distributor for further details on these materials or the products contained therein.

Generally the listed company name and the brand name are the trademarks or registered trademarks of the respective companies.